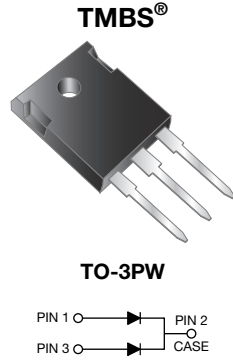


# Dual High-Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low  $V_F = 0.52 \text{ V}$  at  $I_F = 10 \text{ A}$ 


## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

## TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

## MECHANICAL DATA

**Case:** TO-3PW

Molding compound meets UL 94 V-0 flammability rating  
 Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

| PRIMARY CHARACTERISTICS       |                     |
|-------------------------------|---------------------|
| $I_{F(AV)}$                   | 2 x 30 A            |
| $V_{RRM}$                     | 170 V               |
| $I_{FSM}$                     | 260 A               |
| $V_F$ at $I_F = 30 \text{ A}$ | 0.65 V              |
| $T_J$ max.                    | 175 °C              |
| Package                       | TO-3PW              |
| Diode variation               | Dual common cathode |

| MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)                    |                |             |            |
|--|----------------|-------------|------------|
| PARAMETER  | SYMBOL         | V60170PW    | UNIT       |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$      | 170         | V          |
| Maximum average forward rectified current (fig. 1)                                 | $I_{F(AV)}$    | per device  | 60         |
|  |                | per diode   | 30         |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | $I_{FSM}$      | 260         | A          |
| Voltage rate of change (rated $V_R$ )  | $dV/dt$        | 10 000      | V/ $\mu$ s |
| Operating junction and storage temperature range                                   | $T_J, T_{STG}$ | -40 to +175 | °C         |

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) |                      |                                   |             |      |      |               |
|--|----------------------|-----------------------------------|-------------|------|------|---------------|
| PARAMETER  | TEST CONDITIONS      | SYMBOL                            | TYP.        | MAX. | UNIT |               |
| Instantaneous forward voltage per diode  | $I_F = 10\text{ A}$  | $T_A = 25\text{ }^\circ\text{C}$  | $V_F^{(1)}$ | 0.66 | -    | V             |
|  | $I_F = 15\text{ A}$  |                                   |             | 0.72 | -    |               |
|  | $I_F = 30\text{ A}$  |                                   |             | 0.80 | 0.93 |               |
|  | $I_F = 10\text{ A}$  | $T_A = 125\text{ }^\circ\text{C}$ |             | 0.52 | -    |               |
|  | $I_F = 15\text{ A}$  |                                   |             | 0.56 | -    |               |
|  | $I_F = 30\text{ A}$  |                                   |             | 0.65 | 0.73 |               |
| Reverse current per diode  | $V_R = 136\text{ V}$ | $T_A = 25\text{ }^\circ\text{C}$  | $I_R^{(2)}$ | 2.6  | -    | $\mu\text{A}$ |
|  |                      | $T_A = 125\text{ }^\circ\text{C}$ |             | 3.2  | -    | mA            |
|  | $V_R = 170\text{ V}$ | $T_A = 25\text{ }^\circ\text{C}$  |             | -    | 500  | $\mu\text{A}$ |
|  |                      | $T_A = 125\text{ }^\circ\text{C}$ |             | 6.2  | 60   | mA            |

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle  
 (2) Pulse test: Pulse width  $\leq 20\text{ ms}$

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted) |            |                 |          |                    |
|---|------------|-----------------|----------|--------------------|
| PARAMETER   |            | SYMBOL          | V60170PW | UNIT               |
| Typical thermal resistance  | per diode  | $R_{\theta JC}$ | 0.9      | $^\circ\text{C/W}$ |
|   | per device |                 | 0.6      |                    |

| <b>ORDERING INFORMATION</b> (Example) |                |                 |              |               |               |
|---------------------------------------|----------------|-----------------|--------------|---------------|---------------|
| PACKAGE                               | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-3PW                                | V60170PW-M3/4W | 4.5             | 4W           | 30/tube       | Tube          |

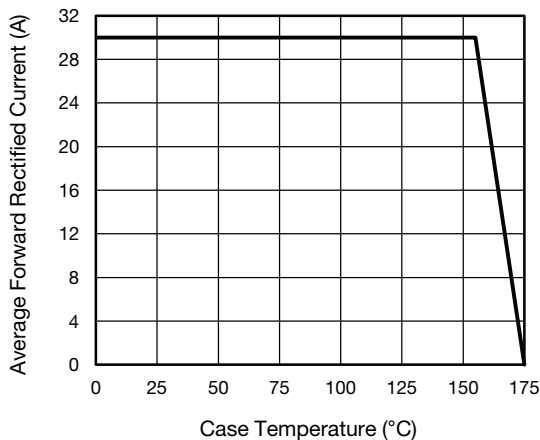
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

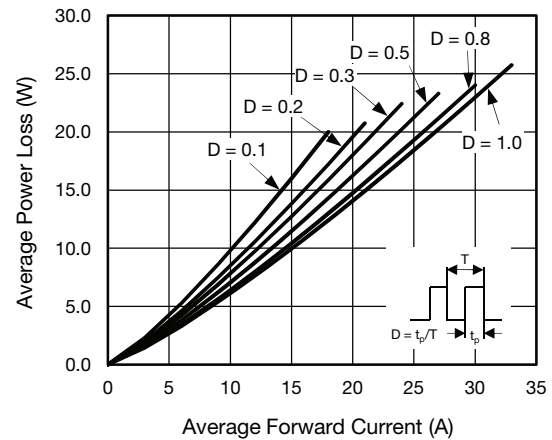


Fig. 2 - Forward Power Loss Characteristics Per Diode

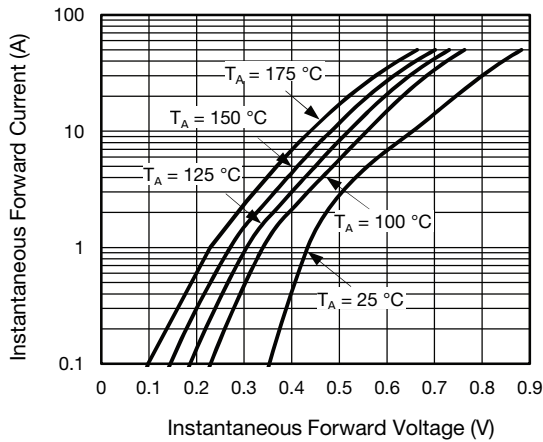


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

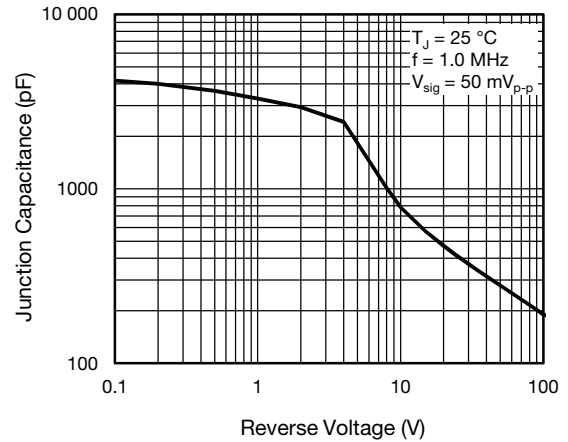


Fig. 5 - Typical Junction Capacitance Per Diode

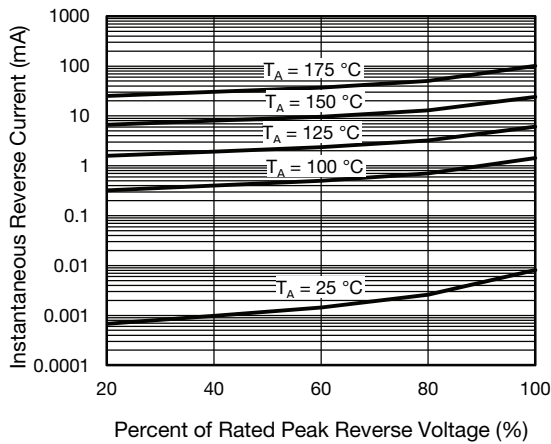


Fig. 4 - Typical Reverse Characteristics Per Diode

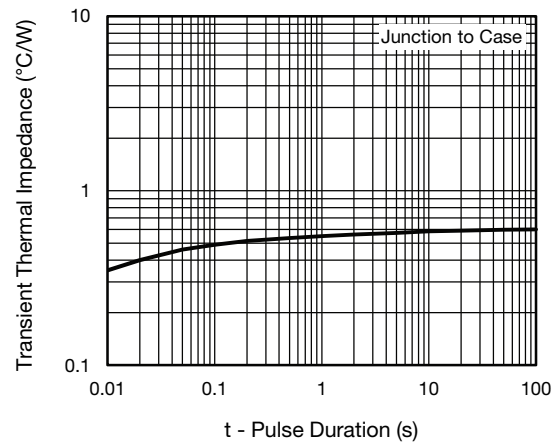
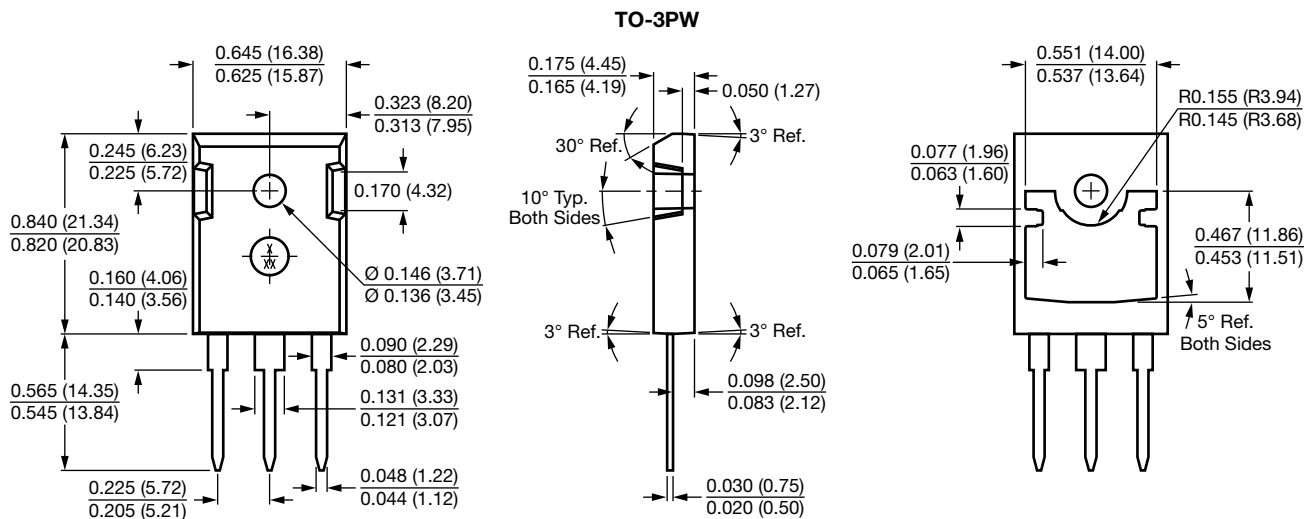


Fig. 6 - Typical Transient Thermal Impedance Per Device

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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